

EAST - [10647700.wsp:1]

File View Edit Tools Window Help

Drafts
 BRS: (phase-changeable)
 Pending
 Active
 L115: (105) ((phase-changeable) or (phas
 L116: (32) 115 and (germanium or stibium
 Failed
 Saved
 (22) (phase-changeable near memory) or
 (2) ("5814527").PN
 (22) (phase-changeable near memory) or
 (1) "3423646".PN
 (1) "3796926".PN
 (1) "4099260".PN
 (1) "4115872".PN
 (22) (phase-changeable near memory) or
 (300) (phase-changeable) or (phase adj d
 (300) (phase-changeable) or (phase adj d
 (105) ((phase-changeable) or (phase adj c
 Favorites
 Tagged (0)
 UDC
 Queue
 Trash

USPAT;EPO;JPO;DERWENT;IBM;TDB
 Plurals
 Highlight all hit terms initially
 Default operator: OR
 115 and (germanium or stibium or tellurium)

BRST... I&F... Image... Text... HTML...

	U	I	Document ID	Issue Date	Pages	Title	Current OR	Current XRef
1	<input type="checkbox"/>	<input type="checkbox"/>	US 6423621 B1	20020723	24	Controllable ovonic phase-change semiconductor memory device and	438/597	257/20; 257/3;
2	<input type="checkbox"/>	<input type="checkbox"/>	US 6329666 B1	20011211	24	Controllable ovonic phase-change semiconductor memory device and	257/3	257/4; 257/41;
3	<input type="checkbox"/>	<input type="checkbox"/>	US 6294452 B1	20010925	22	Controllable ovonic phase-change semiconductor memory device and	438/597	257/20; 257/529;
4	<input type="checkbox"/>	<input type="checkbox"/>	US 6150253 A	20001121	24	Controllable ovonic phase-change semiconductor memory device and	438/597	257/E27.004; 257/E45.002;
5	<input type="checkbox"/>	<input type="checkbox"/>	US 6011757 A	20000104	8	Optical recording media having increased erasability	369/13.35	428/64.1; 430/270.13
6	<input type="checkbox"/>	<input type="checkbox"/>	US 5850378 A	19981215	30	Method and apparatus for recording data on an optical disk and or groove	369/59.11	369/116; 369/275.3;
7	<input type="checkbox"/>	<input type="checkbox"/>	US 5596522 A	19970121	35	Homogeneous compositions of microcrystalline semiconductor material,	365/113	257/3; 257/4;
8	<input type="checkbox"/>	<input type="checkbox"/>	US 5591501 A	19970107	6	Optical recording medium having a plurality of discrete phase change data recording	428/64.1	369/275.1; 369/275.2;
9	<input type="checkbox"/>	<input type="checkbox"/>	US 5362538 A	19941108	10	Optical recording medium	428/64.5	346/135.1; 347/264;
10	<input type="checkbox"/>	<input type="checkbox"/>	US 5335219 A	19940802	37	Homogeneous composition of microcrystalline semiconductor material,	369/288	257/E27.004; 257/E27.103;
11	<input type="checkbox"/>	<input type="checkbox"/>	US 5128099 A	19920707	12	Congruent state changeable optical memory material and device	420/579	148/304; 148/403;